



LOW CAPACITANCE BIDIRECTIONAL TVS DIODE

Features

- Provides ESD Protection per IEC 61000-4-2 Standard:
 Air ±30kV, Contact ±30kV
- IEC61000-4-4 (EFT): ±50 A (5/50ns)
- IEC61000-4-5 (surge): ±6 A (8/20μs)
- Ultra Low Profile (0.4mm), Ideal for Thin Portable Electronics
- 1 Channel of ESD Protection
- Typically Used in Cellular Handsets, Portable Electronics, Communication Systems, Computers and Peripherals
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: X2-DFN1006-2
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.001 grams (approximate)

X2-DFN1006-2

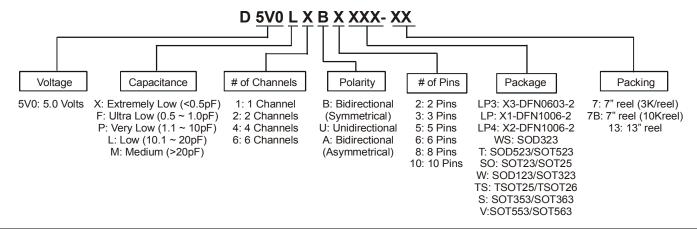






Device Schematic

Ordering Information (Note 4)



Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
D5V0L1B2LP4-7B	Standard	Z	7	8	10,000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Z

Z = Product Type Marking Code Line Denotes Pin 1

D5V0L1B2LP4
Document number: DS35586 Rev. 7 - 2



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Power Dissipation	P _{PP}	84	W	8/20µs, Per Figure 1
Peak Pulse Current	I _{PP}	6	Α	8/20µs, Per Figure 1
ESD Protection – Contact Discharge	V _{ESD_Contact}	±30	kV	IEC 61000-4-2 Standard
ESD Protection – Air Discharge	V _{ESD_Air}	±30	kV	IEC 61000-4-2 Standard

Thermal Characteristics

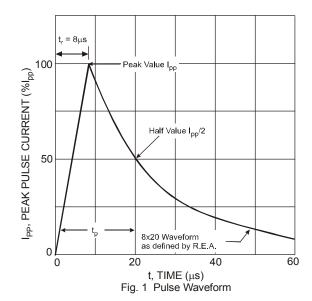
Characteristic	Symbol	Value	Unit
Package Power Dissipation (Note 5)	P _D	250	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	500	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Standoff Voltage	V_{RWM}	_	_	5	V	_
Channel Leakage Current (Note 5)	I _{RM}	1	10	100	nA	V _{RWM} = 5V
Clamping Voltage, Positive Transients	V _{CL}	1111	7.0 9.0 10.5 11.5	9.0 11.0 12.0 14.0	V	$I_{PP} = 1A$, $t_p = 8/20 \mu S$ $I_{PP} = 3.5A$, $t_p = 8/20 \mu S$ $I_{PP} = 5A$, $t_p = 8/20 \mu S$ $I_{PP} = 6A$, $t_p = 8/20 \mu S$
Breakdown Voltage	V_{BR}	6	7	8	V	I _R = 1mA
Differential Resistance	R _{DIF}		0.2	_	Ω	$I_R = 1A$, $t_p = 8/20 \mu S$
Channel Input Capacitance	C _T		15	20	pF	$V_R = 0V$, $f = 1MHz$

Notes:

^{6.} Short duration pulse test used to minimize self-heating effect.



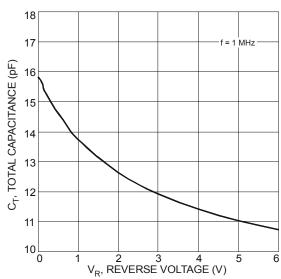
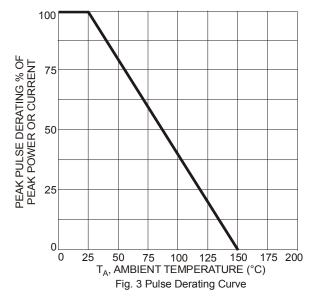


Fig. 2 Typical Total Capacitance vs. Reverse Voltage

^{5.} Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com.





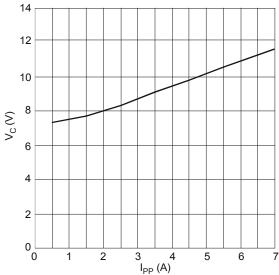


Figure 5 Typical Peak Clamping Voltage V_C vs. Peak Pulse Current I_{PP}

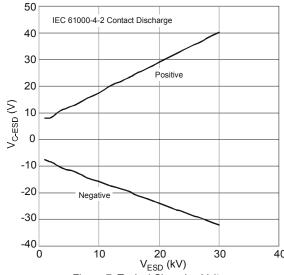
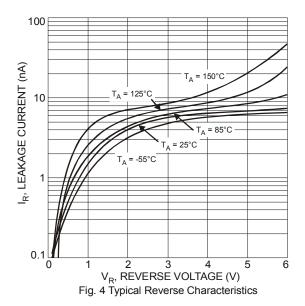


Figure 7 Typical Clamping Voltage vs. Contact Discharge Voltage



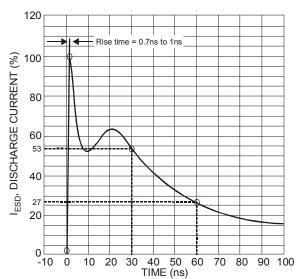


Figure 6 ESD Discharge Current Wave Form IEC 6100-4-2 (330Ω/150pF)

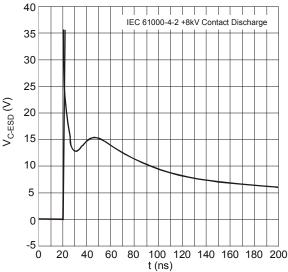
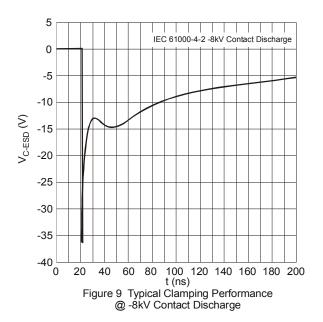


Figure 8 Typical Clamping Performance

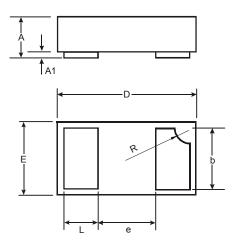
@ 8kV Contact Discharge





Package Outline Dimensions

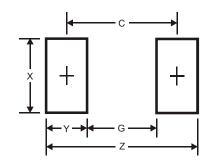
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



X2-DFN1006-2					
Dim	Min	Max	Тур		
Α	0.34	0.4	0.37		
A1	0	0.05	0.03		
b	0.45	0.55	0.50		
D	0.95	1.075	1.00		
Е	0.55	0.675	0.60		
е	_	_	0.40		
L	0.20	0.30	0.25		
R	0.05	0.15	0.10		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	1.1
G	0.3
Х	0.7
Υ	0.4
С	0.7



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